IBM Docket No.: FIS920030397US1

Declaration and Power of Attorney for Patent Application

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: A MANUFACTURABLE METHOD AND STRUCTURE FOR DOUBLE SPACER CMOS WITH OPTIMIZED NFET/PFET PERFORMANCE

the specification of which (cl	neck one)		
X is attact	ned hereto.		
was filed	on as /	Application Serial No.	and was amended on
I hereby state that I have revie by any amendment referred		ntents of the above-identified spe	cification, including the claims, as amende
I acknowledge the duty to dis of Federal Regulations, §1.5		aterial to the patentability of this a	pplication in accordance with Title 37, Cod
I hereby claim-foreign priority certificate listed below and hat that of the application on wh	ive also identified below any f	ited States Code, §119 of any for oreign application for patent or inv	oreign application(s) for patent or inventor ventor's certificate having a filing date before
Prior Foreign Appl	ication(s):		
Number	Country	Day/Month/Year	Priority Claimed
subject matter of each of the the first paragraph of Title 35	claims of this application is r i, United States Code, §112, d in Title 37, Code of Feder or PCT international filing da	not disclosed in the prior United S , I acknowledge the duty to discloral ral Regulations, §1.56 which oc	oplication(s) listed below and, insofar as the tates application in the manner provided by use information material to the patentability curred between the filing date of the prior
Serial No.	10115.	Filing Date	Status
are believed to be true; and t made are punishable by fine	further that these statements or imprisonment, or both, ur	were made with the knowledge	statements made on information and belie that willful false statements and the like so he United States Code and that such willfu
As a named inventor, I here application and transact all b	by appoint the following attusiness in the Patent and Tr	orneys and/or agents listed und ademark Office connected there	er Customer No. 29154 to prosecute this with.
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